

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,888,188 B2
APPLICATION NO. : 10/086942
DATED : May 3, 2005
INVENTOR(S) : Cem Basceri

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Col. 2, line 57 -

Replace "regions of capacitors to have. variable concentration at" With --regions of capacitors to have variable concentration at --

Col. 5, line 39 -

Replace " \AA to about 500 \AA in particular embodiments, layers 122 and " With -- \AA to about 500 \AA . In particular embodiments, layers 122 and--

Col. 7, line 4 -

Replace "embodiment, the formation of dielectric materials 12, 124" With --embodiment, the formation of dielectric materials 122, 124--

Col. 7, line 65 -

Replace " layer comprises a thickness of from about 1 \AA to about 50" With --layer comprises a thickness of from about 10 \AA to about 50--

Signed and Sealed this

Fifteenth Day of August, 2006

A handwritten signature in black ink, reading "Jon W. Dudas". The signature is stylized, with a large loop for the 'J' and a cursive 'Dudas'.

JON W. DUDAS

Director of the United States Patent and Trademark Office